

GENERAL PURPOSE APPLICATION.

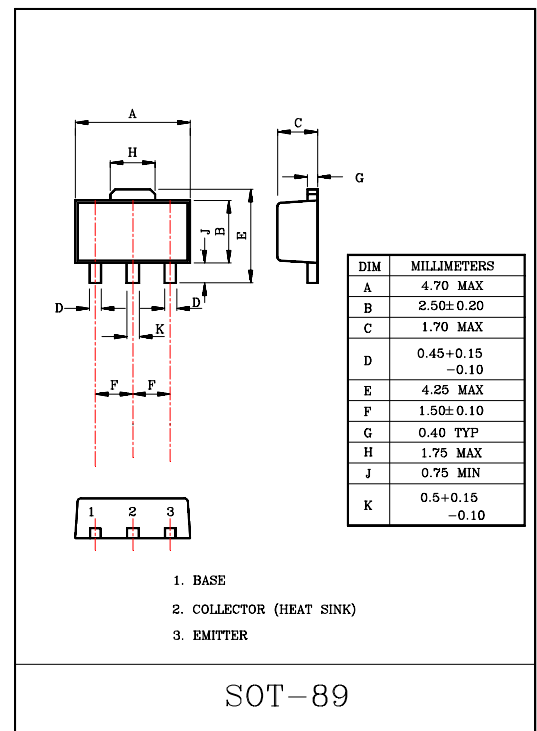
FEATURES

- 1W (Mounted on Ceramic Substrate).
- Small Flat Package.
- Complementary to KTC4374.

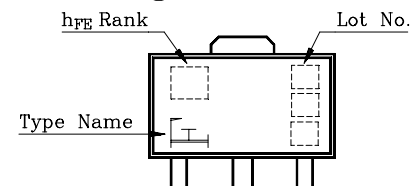
MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V_{CEO}	-80	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-400	mA
Base Current	I_B	-80	mA
Collector Power Dissipation	P_C	500	mW
	P_{C^*}	1	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

P_{C^*} : KTA1662 mounted on ceramic substrate (250mm²x0.8t)



Marking



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=-80V, I_E=0$	-	-	-100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5V, I_C=0$	-	-	-100	nA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10mA, I_B=0$	-80	-	-	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE}=-2V, I_C=-50mA$	70	-	240	
	$h_{FE(2)}$	$V_{CE}=-2V, I_C=-200mA$	40	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-200mA, I_B=-20mA$	-	-	-0.4	V
Base-Emitter Voltage	V_{BE}	$V_{BE}=-2V, I_C=-5mA$	-0.55	-	-0.8	V
Transition Frequency	f_T	$V_{CE}=-10V, I_C=-10mA$	-	120	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, I_E=0, f=1MHz$	-	14	-	pF

Note : h_{FE} Classification O:70~140, Y:120~240

